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A theoretical study of formaldehyde adsorption and decomposition on a WC (0001) surface†

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A lot of research attention has been paid to designing and exploring efficient adsorbents for HCHO adsorption and decomposition. Herein, we have demonstrated a highly active material, WC, for HCHO adsorption through first-principles calculations. Due to the exposed three-coordinated W atoms (W_{3c}) of the WC (0001) surface, HCHO molecules can be settled on the WC (0001) surface through newly formed O_F-W_{3c} and/or C_F-W_{3c} bonds, forming different adsorption configurations. When settled on the WC (0001) surface, the molecular configuration of the HCHO molecule and the corresponding C_F-H_F and C_F-O_F bond lengths would be greatly changed. Due to the enlarged C_F-H_F and C_F-O_F bond lengths, the adsorbed HCHO molecules tend to dissociate through two possible pathways; these are the two-step C_F-H_F bond scission or the one-step C_F-O_F bond scission. The former results in two H adatoms and a CO molecule chemisorbed to the surface and the latter produces an O adatom and a CH_2 group on the surface. Further CI-NEB calculations demonstrate that the pre-adsorbed O atom has little influence on the first C_F-H_F bond scission and the C_F-O_F bond scission, while promoting the second C_F-H_F bond scission. Considering the dissociative products, H and CH_2 have the potential to couple into a CH_3 group (or even a CH_4 molecule) and two CH_2 groups may couple into a C_2H_4 molecule. In the end, we propose that OH ions may couple with the dissociative products of HCHO, so an alkali solution could be used to post-process the WC (0001) surface to restore its surface active sites. These results demonstrated the potential of WC in HCHO sensing and abatement.

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1. Introduction

Formaldehyde (HCHO) sensing and detection in both residential and industrial environments has attracted more and more attention because of the damage caused to the human body by this colorless, pungent-smelling gas is enormous.^{1–4} In the past few decades, various technologies for gas detecting have been developed including spectrophotometry, chromatography, polarography and so on.^{5–9} However, the applications in real-time monitoring of indoor volatile organic compounds (VOC) of these technologies have been limited due to the requirements of accurate sample collection, expensive and bulky instrumentation and skilled operators. In recent years, because of their high activity and sensitivity, fast response and easy-operation, a variety of sensing materials, such as supported noble

metals,^{10–12} and metal oxides,^{13,14} have been developed for portable real-time measurement and elimination of HCHO.

Noble metals, especially platinum (Pt), show the most excellent activity for HCHO removal and have attracted a lot of attention.¹⁵ However, their wide application is hindered by their scarceness and preciousness. Though metal oxides as promising alternatives for HCHO removal have been extensively studied,^{16–19} most of their performances are unsatisfactory on account of the high reaction temperature. Therefore, it is crucial to develop novel cost-effective adsorbents possessing a good adsorption capacity, large specific surface area and high potential for HCHO decomposition.

In the early 1970s, the transition metal carbide, WC has been demonstrated to possess many of the desirable catalytic properties of “noble” metals (such as Pt) with respect to hydrogen oxidation and hydrogenolysis reactions, because its electronic density of states (DOS) near the Fermi level resembles that of Pt.^{20–22} Whereafter, considerable attention has been paid to the catalytic properties of transition metal carbide for a variety of reactions. For example, in 1998, MoC and WC have been used as active catalysts for the oxidation of CH_4 to synthesis gas.²³ In recent years, there have been several attempts to apply transition metal carbides as electro catalysts for electrochemical energy conversion devices, such as for CH_3OH or H_2 fuel cells.^{24,25} Transition metal carbide have also been identified as

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a promising catalyst for selective reduction of CO₂ by H₂.²⁶ Recently, their high catalytic activities towards hydrogen evolution reaction (HER) and oxygen reduction reaction (ORR) have been demonstrated.^{27–30}

Though their catalytic properties have been widely studied, the activity of transition metal carbides towards HCHO adsorption and decomposition has never been studied. Whether the transition metal carbides can be used as activation materials for HCHO sensing and elimination? It's well known that when target gases comes in contact with the adsorbents, the adsorption of gas on adsorbents and the electron exchange between them will change the conductivity of the adsorbents. This simple working mechanism indicates that the quality of sensors is determined by the interaction between target gases and sensing materials. What's more, adsorption and decomposition on adsorbents are the most effective elimination mechanism for HCHO removal. Therefore, it is very meaningful to study the adsorption and decomposition behaviors of HCHO towards transition metal carbides for the detecting and removing HCHO in air.

In this work, we have studied the HCHO adsorption behaviors on the WC (0001) surface by first principles calculations for the first time, which can be took as an example to investigate the catalytic properties of transition metal carbides towards HCHO. Total energy calculation results indicated that the WC (0001) surface exhibits excellent adsorption properties for HCHO molecules due to the activity of exposed W_{3c} atoms at the surface. The dissociation behavior of HCHO on clean and O-pre-adsorbed WC (0001) surface has been characterized. Based on the calculated reaction energy paths, the possible formation mechanisms of CH₃ group (or even CH₄) and C₂H₄ are also been presented. OH ions may be used to couple with the dissociative products of HCHO on the surface. Those findings in this work may hold the promise for the development of HCHO sensing and elimination.

2. Computational methods

We performed DFT calculations within the Perdew–Burke–Ernzerhof (PBE) generalized gradient approximation³¹ and the projected augmented wave (PAW) method^{31–33} which was implemented in the Vienna ab initio simulation package (VASP). The cutoff energy for the plane wave basis set is 400 eV. Moreover, the convergence threshold was set to be 10^{−4} eV in energy and 10^{−2} eV Å^{−1} in force for ground state geometry optimizations. The calculated lattice parameters for the hexagonal WC bulk ($a = b = 2.916$ Å, $c = 2.842$ Å) are almost consistent with the experimental values ($a = b = 2.906$ Å, $c = 2.837$ Å),³⁴ suggesting that the calculations may provide 98% accuracy in describing the geometry structures. According to previous literatures, the most thermodynamically stable surface of WC material is the (0001) surface,^{35,36} and hence the WC (0001) surface is modeled and its performance in HCHO sensing and elimination is investigated. The WC (0001) surface model as shown in Fig. S1† is constructed from the optimized bulk unit cell. Based on our experience and literature reports, a vacuum thickness of 15 Å is adopted in building the periodic

slab models to avoid interaction between two adjacent periodic images.^{37,38} And a Monkhorst–Pack of 3 × 3 × 1 *K*-points is applied for the Brillouin-zone integration. For the WC (0001) surface, a supercell slab consisting of eight atomic monolayers including 32 W atoms and 32 C atoms is constructed and the optimized geometry structure is shown in Fig. S1.†

Before adsorption, the isolated HCHO molecule is simulated in a large cubic cell of 15 Å in length and the O, C, H atom of HCHO are denoted as O_F, C_F, H_F here. For all the adsorption configurations, the atomic positions of the four lower atomic layers are fixed at their bulk geometry and the four upper layers are allowed to fully relax. The adsorption energies are calculated following the equation $E_{\text{ads}} = E_{\text{HCHO}} + E_{\text{surface}} - E_{\text{HCHO/surface}}$, where $E_{\text{HCHO/surface}}$, E_{HCHO} , and E_{surface} are the total energies of the WC (0001) surface with adsorbed HCHO molecule, the isolated HCHO molecule and the clean WC (0001) surface, respectively. Density of states (DOS), partial density of states (PDOS) and difference charge density are obtained at the optimized geometry structures. Moreover, we have investigated the possible dissociative pathways for adsorbed HCHO molecules, and the coupling pathways of the dissociative products by climbing image nudged elastic band (CI-NEB) method (finding saddle points and minimum energy paths between known reactants and products).

3. Results and discussion

3.1 Molecular adsorption of HCHO on WC (0001) surface

In view of the electronegativity of the O_F/C_F atoms and surface W atoms, new O_F–W and/or C_F–W bonds may be formed in the adsorption systems.³⁷ Moreover, three possible adsorption sites of O_F/C_F atoms on the WC (0001) surface as shown in Fig. S1† are selected to compare their adsorption energies. On WC (0001) surface, many various adsorption configurations for HCHO molecules are considered: O_F atom of HCHO molecule on T/H/F site with HCHO molecule almost parallel/perpendicular to the surface; C_F atom of HCHO molecule on T/H/F site with the symmetrical axis of HCHO molecule parallel to the surface; O_F atom of HCHO molecule on T/H/F site and C_F on adjacent adsorption sites with the C_F–O_F bond almost parallel to the surface.

Through total energy calculations, the stable molecule adsorption configurations for HCHO on the WC (0001) surface are determined and depicted in Fig. 1. As shown in Fig. 1(a), the O_F atom takes up the T site and binds to a surface W_{3c} atom with the adsorption energy of 0.70 eV, forming a slantwise configuration. The bond length of newly formed O_F–W_{3c} bond is about 2.13 Å. Moreover, the C_F–H_F bond of HCHO is slightly shortened to 1.10 Å (0.02 Å shorter) and the C_F–O_F bond of HCHO is lengthened to 1.25 Å, 0.04 Å longer than that of isolated HCHO molecule.

In the configuration shown in Fig. 1(b), HCHO interacts with WC (0001) surface through the O_F occupying the T site and bond to one surface W_{3c} atom, meanwhile the C_F atom taking up the F site and bond to two surface W_{3c} atoms, in the form of ‘hobbyhorse-like’ construction. The bond lengths of newly formed O_F–W_{3c} and C_F–W_{3c} are 2.00 Å and 2.42 Å, respectively



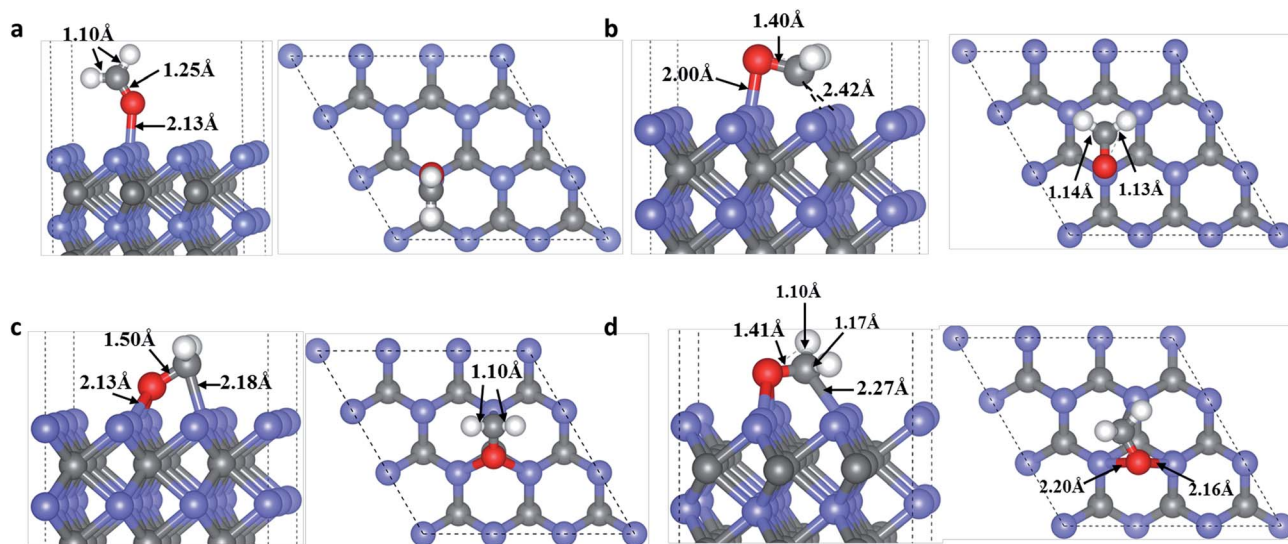


Fig. 1 Side (left) and top (right) views of the optimized structure of molecule adsorption configurations for HCHO molecules on WC (0001) surface. (a) Shows the slantwise adsorption; (b) and (c) and (d) represent the 'hobbyhorse-like' adsorption states. Red, blue, gray and white balls represent O atoms, W atoms, C atoms and H atoms, respectively.

and the adsorption energy is 1.86 eV. Meanwhile, the C_F-O_F bond of adsorbed HCHO in this type is lengthened to 1.40 Å, 0.19 Å longer than that of isolated HCHO molecule. And the C_F-H_F bond lengths are also slightly lengthened to 1.13 Å and 1.14 Å, respectively.

HCHO can also chemisorb to WC (0001) surface through two newly formed O_F-W_{3c} bonds and one newly formed C_F-W_{3c} bond, as shown in Fig. 1(c) and (d), and the adsorption energies are 1.89 eV and 2.08 eV, respectively. These two adsorption configurations also look like 'hobby-horse'. In Fig. 1(c), O_F and C_F atoms locate at the H site and top site, respectively, with newly formed O_F-W_{3c} and C_F-W_{3c} bond lengths of 2.13 Å and 2.18 Å. And the C_F-O_F bond is lengthened to 1.50 Å with the C_F-H_F bond lengths shortened to 1.10 Å. While in Fig. 1(d), the bonding situation is more complicated with two different O_F-W_{3c} bond lengths (2.20 Å and 2.16 Å) and the C_F-W_{3c} bond length is 2.27 Å. As well, the C_F-O_F bond is lengthened to 1.41 Å while one C_F-H_F bond is shortened to 1.10 Å and the other is lengthened to 1.17 Å. It is worth noting that the adsorption energies of HCHO on WC (0001) surface are comparable to those for HCHO adsorption on other catalyst surfaces, such as TiO_2 (ref. 38) and $WO_{2.9}$ (ref. 37) surface, indicating that WC is a suitable catalyst material for HCHO sensing and remove. What's more, C_F-O_F bonds of HCHO are stretched at different levels in different adsorption configurations. This is mainly because the interaction between O_F/C_F and surface atoms and newly formed O_F-W/C_F-W bonds weaken the adjacent C_F-O_F bonds. Correspondingly, the interactions between H_F and C_F are influenced, leading to shortened or lengthened C_F-H_F bonds.

3.2 Electronic properties of WC (0001) surface with HCHO adsorption

The electronic structure of WC (0001) surface has been studied by further analysis of total and partial density of states (DOS and

PDOS). As seen from the DOS and PDOS of clean WC (0001) shown in Fig. S2,† the WC (0001) surface is metallic and the density of states near the Fermi level mainly originate from W atoms, in accordance with previous report,³⁹ suggesting that the interaction between the surface and HCHO molecule is primarily the charge transfer between surface W atoms and HCHO molecule. Therefore, O_F/C_F atoms of HCHO molecules prefer to adsorb on the top site of surface W atoms, as shown in Fig. 1. Fig. 2 presents the DOS and some atomic PDOS of the HCHO adsorbed WC (0001) surface in stable configurations presented in Fig. 1. To facilitate comparison, the DOS of clean WC (0001) surface is always shown and the Fermi level of WC (0001) surface is assigned at 0 eV. Obviously, new electronic states occur at around -22.5 eV after HCHO adsorption. The PDOS for the C_F/O_F atom and for the corresponding W_{3c} surface atom which is bound to the C_F/O_F atom are considered. The PDOS of the C_F/O_F atom is broadly dispersed compared with that for HCHO gas-phase (see Fig. S2†) and an overlap between C_F and W_{3c} atom and between O_F and W_{3c} atom can be clearly seen. The broadening C_F/O_F PDOS means the weakened interaction between C_F and O_F atom, which is the underlying reason for C_F-O_F bond length increase in the adsorption systems. Moreover, the PDOS broadening and overlap indicate the obvious charge redistribution and strong interaction between C_F/O_F and surface W atoms in newly formed bonds of C_F-W_{3c} and O_F-W_{3c} .

To understand the local charge transfer between the stable adsorbed HCHO molecules and WC (0001) surface, we studied the charge density difference originated from adsorption, as shown in Fig. 3, in which the blue wireframes denote loss of electrons while yellow wireframes denote gain of electrons. Obviously, for the slantwise adsorption state shown in Fig. 1(a), electron only transfers from surface W atom to the O_F atom and charges in HCHO molecule are redistributed, leading to newly formed O_F-W bond and extended C_F-O_F bond. For adsorption



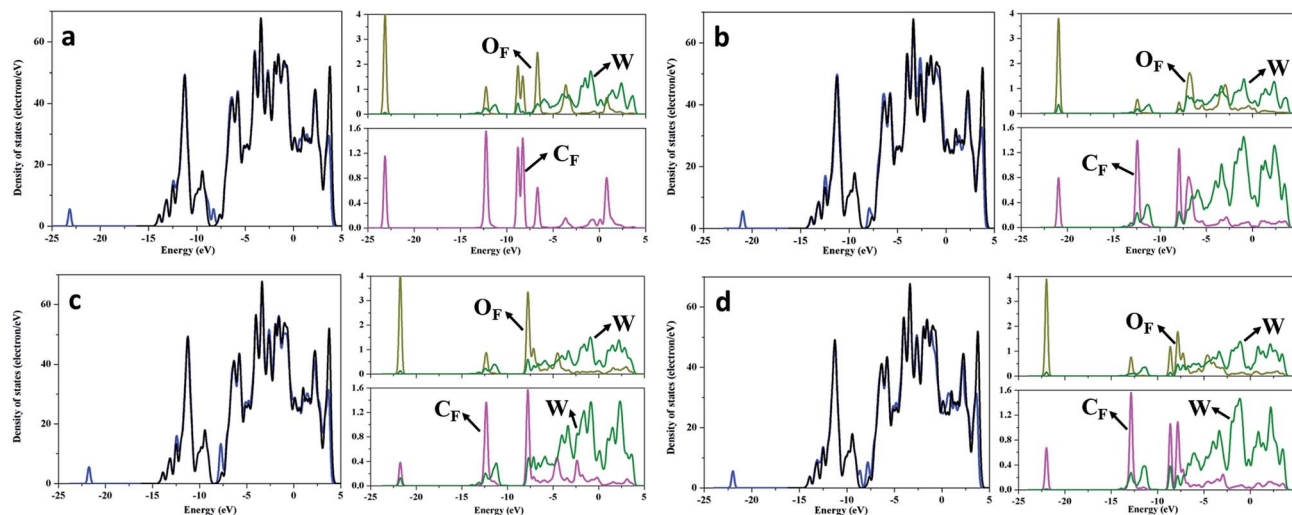


Fig. 2 DOS and PDOS for HCHO adsorbed WC (0001) surface. The curves in (a)–(d) are corresponding to the adsorption configurations shown in Fig. 1(a)–(d), respectively. The black curves present TDOS for WC (0001) surface and TDOS of the clean surface is always plotted to facilitate comparison. The blue curves denote DOS for WC (0001) surfaces with adsorbed HCHO molecules. PDOS of C_F, W and O_F atoms are denoted by pink, olive and dark yellow curves, respectively. The Fermi level of WC (0001) surface is assigned at 0 eV.

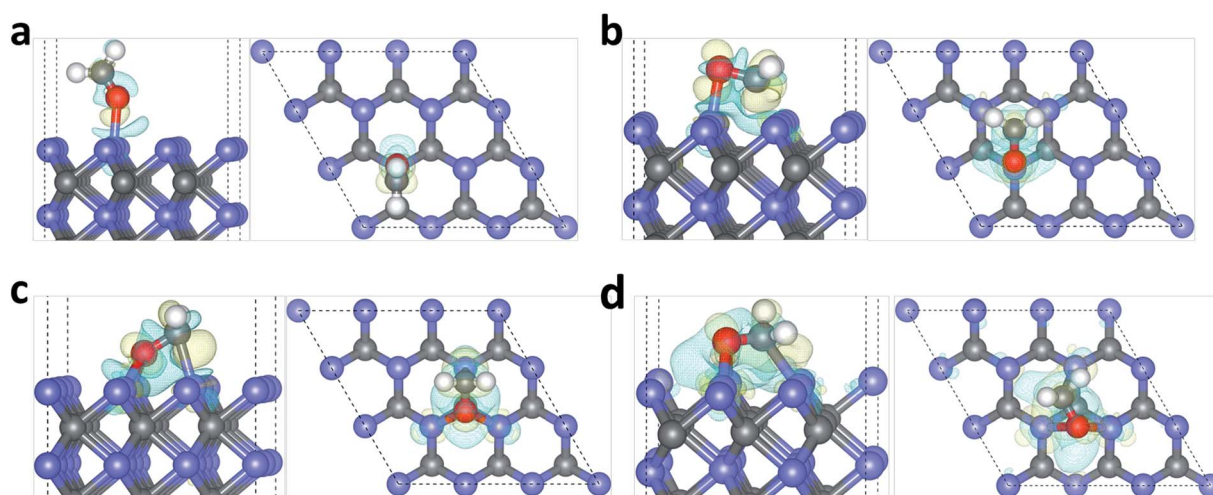


Fig. 3 The isosurface of the difference charge density with the isovalue of 0.003 \AA^{-3} and the blue (yellow) wireframes denote loss (gain) of electrons. Red, blue, gray and white balls represent O atoms, W atoms, C atoms and H atoms, respectively.

configurations shown in Fig. 1(b)–(d), there is obvious charge transfer from the surface W_{3c} atom to O_F atom and from the W_{3c} atom to C_F atom as shown in Fig. 3(b)–(d), indicating the strong binding and interaction between HCHO molecules and the WC (0001) surface. Similarly, the charge redistribution occurs in adsorbed HCHO molecules, in accordance with the broadly dispersed PDOS of C_F and O_F atoms, which is the cause of the C_F–O_F bond increase.

3.3 Decomposition of HCHO on WC (0001) surface

To investigate the possibility of HCHO dissociation on WC (0001) surface, we start with the most stable molecule adsorption configuration shown in Fig. 1(d), which means the initial states are the chemisorbed HCHO molecule on WC (0001)

surface. Herein, two possible dissociative paths have been considered, namely the two-step C_F–H_F bond scission and the one-step C_F–O_F bond scission in view of the weakened C_F–H_F and C_F–O_F bond in adsorbed HCHO molecule. The product coadsorption configurations with the lowest energies are firstly determined through total energy calculations.

As presented in Fig. 4(a), in the two-step C_F–H_F dissociation reaction, the first C_F–H_F bond scission products are one H atom and one formyl group adsorbed to the surface. The transition states are determined as those structures of saddle points obtained by CI-NEB method. The minimum energy path for dehydrogenation reaction of HCHO determined by CI-NEB method is shown with the overall reaction barrier of only 0.24 eV, which is pretty low compared with those reported values and can be easily surmounted.^{37,40} The energy change



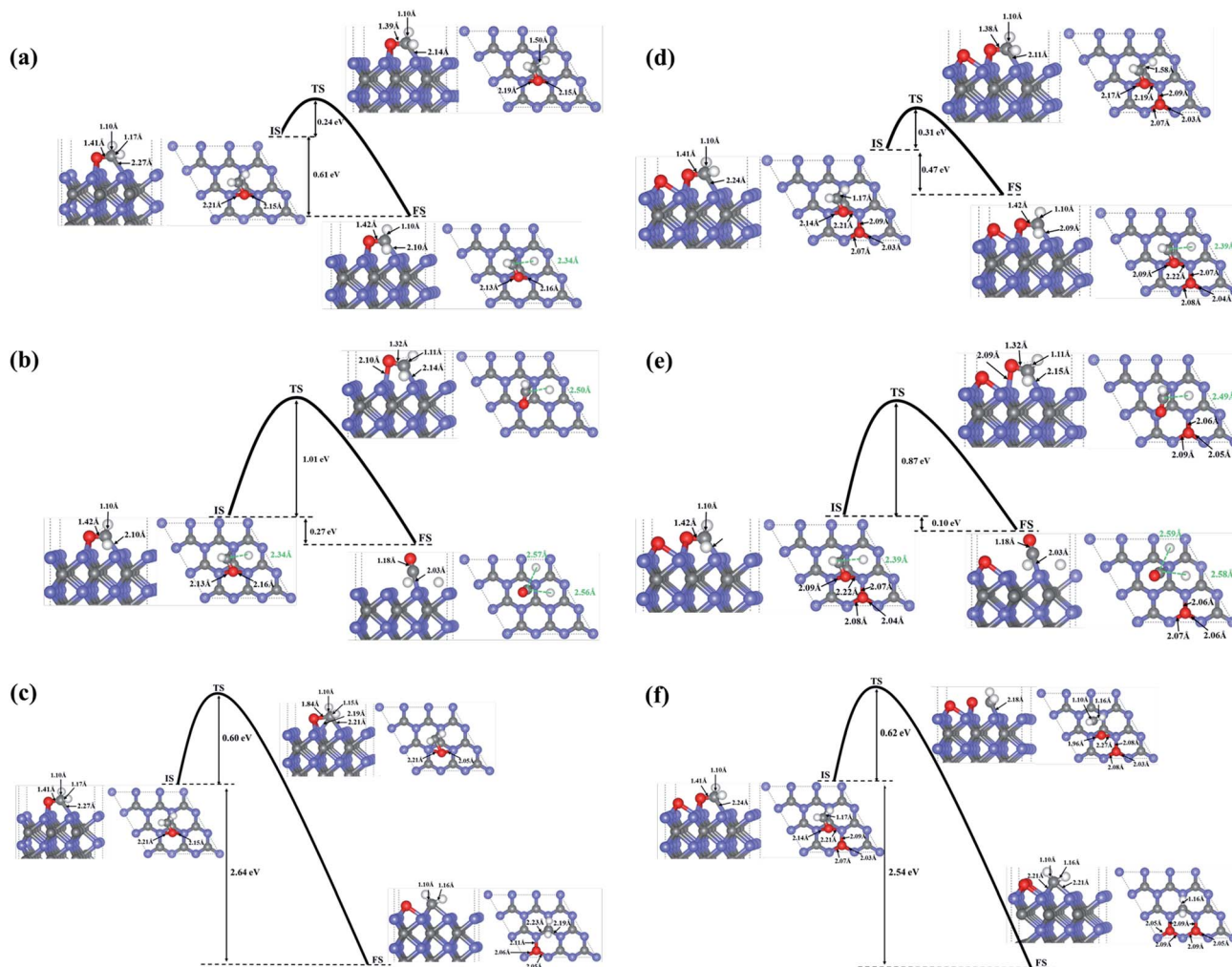


Fig. 4 The minimum energy paths for bond scission reactions of HCHO molecule adsorbed on the surface in the stable configuration as shown in Fig. 1. (d): (a), (b) and (c) are the first-step C–H bond dissociation, second-step C–H bond dissociation and the C–O bond dissociation on the clean WC (0001) surface; (d), (e) and (f) present the first-step C–H bond dissociation, second-step C–H bond dissociation and the C–O bond dissociation on the O pre-adsorbed WC (0001) surface. Blue, gray and white balls represent W atoms, C atoms and H atoms, respectively.

between the initial and final state is -0.61 eV (an exothermic process). The bond lengths of C_F-O_F , C_F-H_F and O_F-W_{3c} bond in the transition state (TS) are quite close to those of the initial state (IS), meaning that the TS is more reactant-like than product-like. After the dehydrogenation reaction, the bond lengths of C_F-O_F bonds in CHO structure are slightly lengthened to 1.42 Å, while bond length of one O_F-W_{3c} bond is shortened to 2.13 Å with the other length almost unchanged. We should note that the C_F-W_{3c} bond length is obviously shortened by 0.17 Å, which means the strengthening of C_F-W_{3c} bond.

The second C_F-H_F bond scission will produce one more H adatom and a chemisorbed CO molecule towards WC (0001) surface, shown in Fig. 4(b). This dehydrogenation reaction needs to across the transition state with an energy barrier of 1.01 eV, and the energy change between the initial and final state is -0.27 eV (an exothermic process). The bond length of C–O bonds in chemisorbed CO molecule is 1.18 Å, and the length of corresponding C–W bond between CO molecule and

the surface is 2.03 Å. In consideration of the huge gap between the two bond scission barriers, HCHO molecules adsorbed on WC (0001) surface prefer to decompose into H adatom and CHO group under mild conditions. Nevertheless, the barrier of 1.01 eV for the second C_F-H_F bond scission could be overcome in some catalytic reactions under combined conditions, such as electrocatalysis and thermocatalysis.⁴⁰

The reaction pathway for the C_F-O_F bond scission of adsorbed HCHO molecule is presented in Fig. 4(c). The C_F-O_F bond scission is accompanied by a rotation of C_F-H_F bonds with the bond length almost unchanged. The reaction needs to across an energy barrier of 0.60 eV. Another notable fact is that the reaction is a strong exothermic process and the energy change between the initial and final state is -2.64 eV. The dissociative products, both CH_2 and O adatom, take up the on-top-C sites. Bond lengths of C–W bonds between chemisorbed CH_2 group and WC (0001) surface are 2.23 Å and 2.19 Å, and the lengths of corresponding O–W bonds between O adatom and the surface are 2.05 Å, 2.06 Å and 2.11 Å.



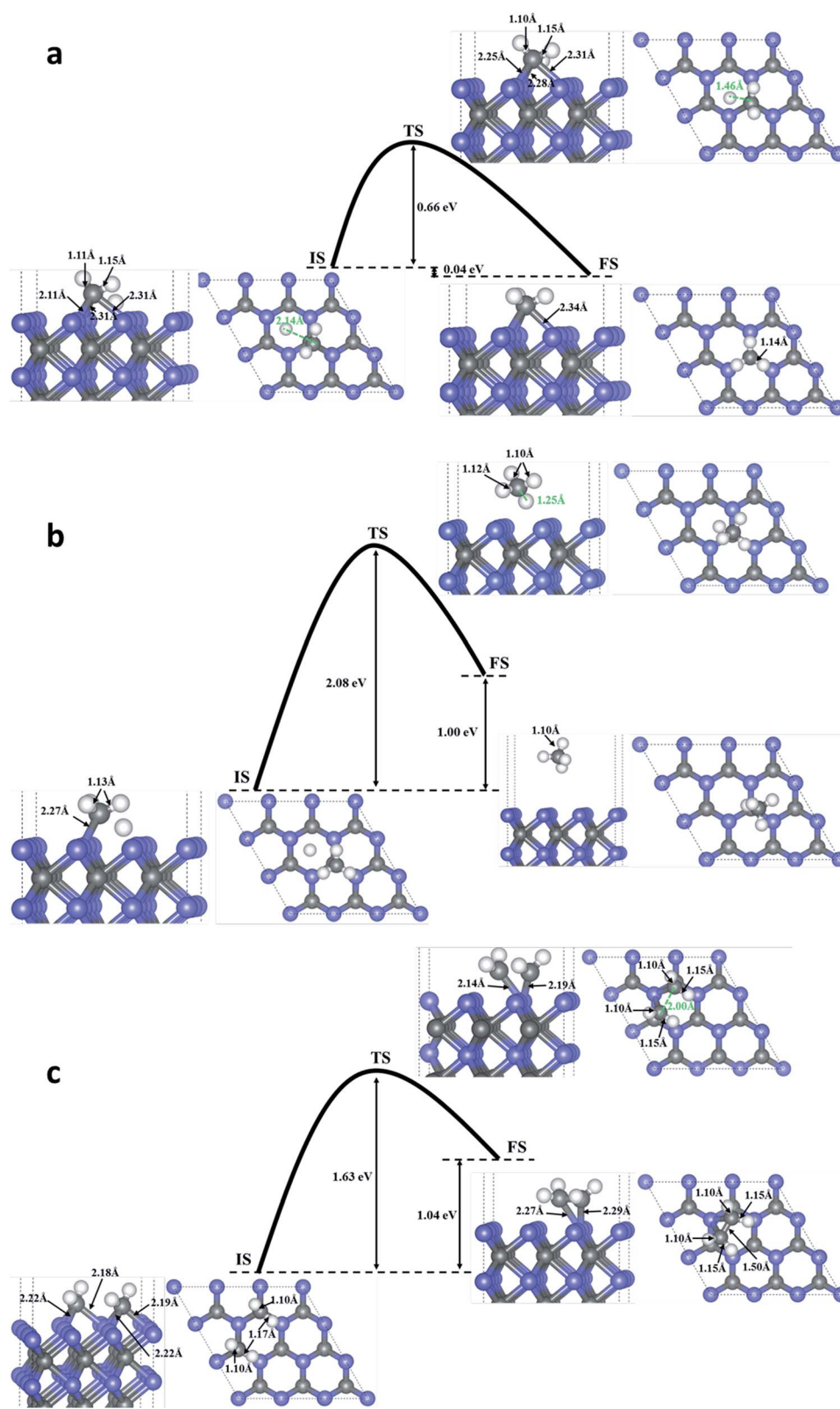


Fig. 5 The minimum energy path for coupling between the products of H atom and CH_2 produced by HCHO dissociation: (a) H atom and CH_2 couple to CH_3 ; (b) H atom and CH_3 couple to CH_4 ; (c) two CH_2 combine to C_2H_4 . Blue, gray and white balls represent W atoms, C atoms and H atoms, respectively.



Both direct C_F-H_F and C_F-O_F bond scission processes have small energy barriers and are exothermic, indicating the process are favored on WC (0001) surface and numerous of the dissociation products, CHO, CO, H, CH₂, and O can be produced on the surface. The barrier for the C_F-H_F dissociation is slightly lower than that for the C_F-O_F dissociation by 0.36 eV, meaning that the former is kinetically more favored than the latter, while the latter is thermodynamically more favorable than the former due to larger released energy (2.64 eV vs. 0.61 eV). In any case, WC is a suitable catalyst material for HCHO adsorption and dissociation and HCHO sensing and remove on WC (0001) surface is quite feasible.

Considering that surface oxygen adatom which stabilizes at the on-top-C site may be active in HCHO adsorption and dissociation reactions, the influence of surface oxygen on HCHO adsorption and dissociation was studied here. It is found that the surface oxygen adatom wouldn't abstract H directly from the HCHO molecule. The adsorption configurations and the corresponding adsorption energies of HCHO on WC (0001) surface are almost unaffected by the presence of one O atom on the surface. What's more, based on total energy calculations, the H atom originated from the dehydrogenation reaction in the two-step C_F-H_F bond scission will occupy a free on-top-C site rather than stick to the pre-adsorbed O atom (the energy difference between these two states is 1.18 eV). The energy barrier of the first C-H bond dissociation is 0.31 eV, which is 0.07 eV higher than that on the clean surface. While the energy barrier of the second C-H bond scission is reduced to 0.87 eV (excluding the interaction energy of 0.032 eV, which is defined as the difference between the energies of the co-adsorbed

configuration and infinite separation state where each surface specie in a separate unit cell at its most stable site) with an energy change between IS and FS of -0.10 eV. The C_F-O_F bond scission energy barrier is slightly increased by 0.02 eV. Thus, we concluded that the surface adsorbed O atom will have slight influence on the C-H and C-O bond breakage of the adsorbed HCHO molecule, and will promote the decomposition of CHO to CO + H. The minimum energy paths of direct C_F-H_F and C_F-O_F bond scissions on the O pre-adsorbed surface are shown in Fig. 4(d), (e) and (f), respectively.

We further considered the possible coupling between the products, H atom and CH₂ produced by HCHO dissociation on WC (0001) surface. Fig. 5(a) indicates that the energy barrier for H and CH₂ coupling to CH₃ is 0.66 eV with the energy change of -0.04 eV (an exothermic reaction). We can speculate that CH₃ may further couple with another H to CH₄ with an energy barrier of 2.08 eV and energy change of 1.00 eV (Fig. 5(b)). If an energy barrier of 1.63 eV is overwhelmed, two CH₂ would combine into C₂H₄ molecule adsorbed on the surface (endothermic by 1.04 eV) and the reaction path is shown in Fig. 5(b). Moreover, a possible mechanism for recovering the surface active sites could be took into account, *i.e.* using the alkaline solution to clean the surface. For example, the CHO can react with the OH ions in alkaline solution, producing physical adsorbed H₂O molecule and chemical adsorbed CO molecule on the surface, as shown in Fig. 6(a). The chemical adsorbed CO molecule may react with the OH ion forming a surface -COOH (Fig. 6(b)), which would further couple with OH to physical adsorbed CO₂ and H₂O molecule (Fig. 6(d)). If the OH attacks the H atom on the surface, a physical adsorbed H₂O molecule

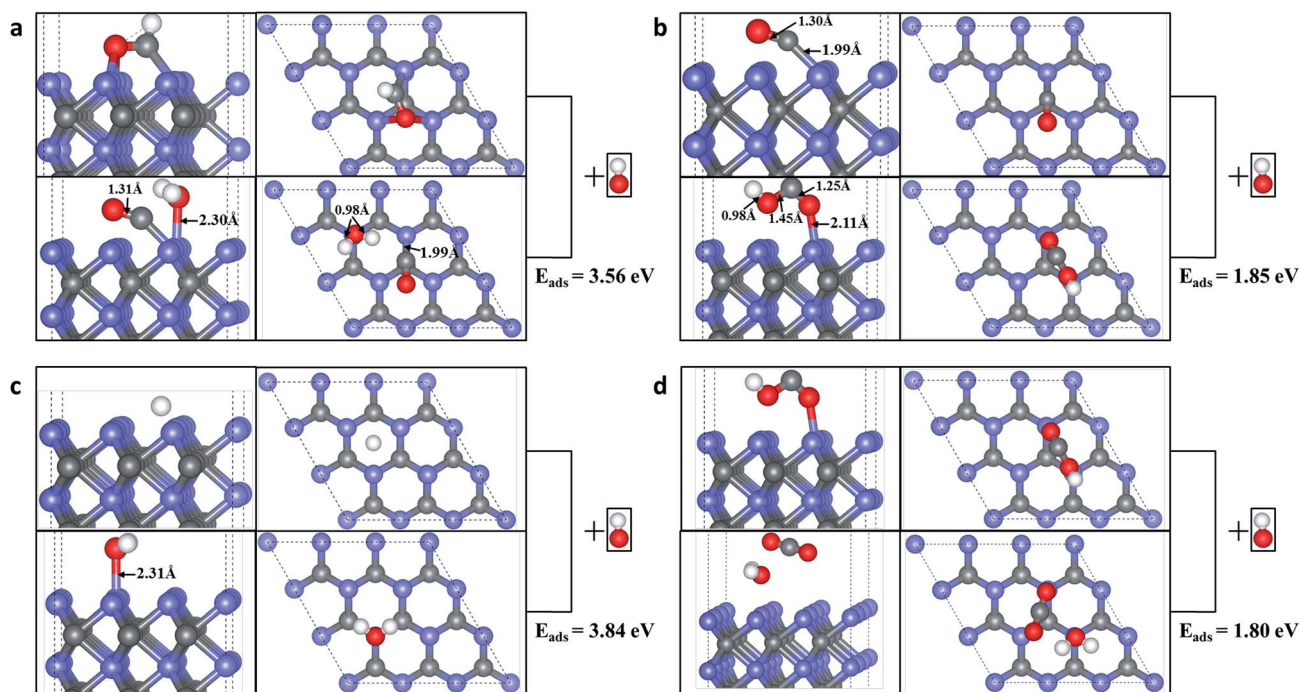


Fig. 6 The adsorption states of OH towards various surface species (a) CHO, (b) CO, (c) H; (d) COOH. Blue, gray and white balls represent W atoms, C atoms and H atoms, respectively. The adsorption E_{ads} are defined as the energy difference between the total energy of CO + H₂O/COOH/H₂O/CO₂ on the surface and the sum of the total energy of CHO/CO/H/COOH on the surface and the energy of isolate OH.



would be formed (Fig. 6(c)). Those physical adsorbed CO₂ and H₂O molecules may desorb from the surface and the active sites of WC (0001) surface could be recovered. More mechanistic studies for the recovering of the active sites of WC (0001) surface will be investigated in detail in our future work.

4. Conclusions

In summary, HCHO adsorption performance on the WC (0001) surface has been systematically investigated based on first-principles calculations, indicating that the WC (0001) surface are appropriate for HCHO sensing and elimination. The calculation results suggest that the exposed W_{3c} atoms at the surface are active for HCHO adsorption and HCHO molecules can fasten on the surface mainly in four types through newly formed O_F-W_{3c} and C_F-W_{3c} bonds. HCHO molecules chemisorbed to WC (0001) surface are inclined to decompose across two C_F-H_F bond scission steps or one C_F-O_F bond scission step, producing H adatom, CHO group, CH₂ group and CO molecule chemical adsorbed on the surface. The intermediates, H adatom and CH₂ group, can couple to CH₃ (even CH₄) and C₂H₄. Furthermore, CHO, H adatom and CO on the surface can react with OH ions in alkaline solution, producing physical adsorbed H₂O and CO₂ molecule, which may easily desorb from the surface and the active sites of WC (0001) surface would be recovered for more HCHO molecules adsorption.

Conflicts of interest

There are no conflicts to declare.

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